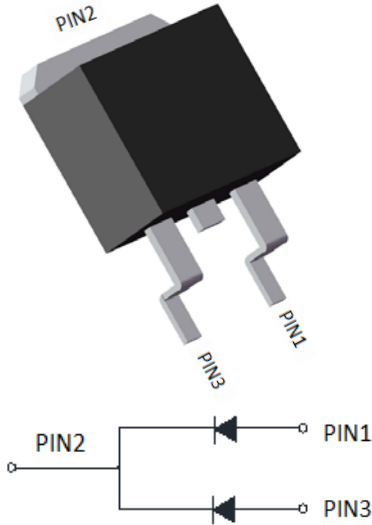


Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-263
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Device marking code			MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Repetitive Peak Reverse Voltage	V_{RRM}	V	100	150	200
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25°C	I_o	A	10		
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25°C	I_{FSM}	A	100		
Current Squared Time @1ms≤t<8.3ms Tj=25°C,	I^2t	A ² s	41		
Storage Temperature	Tstg	°C	-55 ~ +175		
Junction Temperature	Tj	°C	-55 ~ +175		

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Maximum instantaneous forward voltage drop per diode	V_{FM}	V	$I_{FM}=5.0A$	0.85	0.9	0.95
Maximum DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	mA	$V_{RM}=V_{RRM}$ Ta=25°C	0.1		
	I_{RRM2}		$V_{RM}=V_{RRM}$ Ta=125°C	20		

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



MBRB10100CTS THRU MBRB10200CTS

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Thermal Resistance	Between junction and case	R _{θj-c}	°C/W	2.0		

■ Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRB10100CTS THRU MBRB10200CTS	Approximate 1.43	50	2000	8000	Tube
MBRB10100CTS THRU MBRB10200CTS	Approximate 1.43	1000	2000	10000	Reel

■ Characteristics (Typical)

FIG1: I_o -T_c Curve

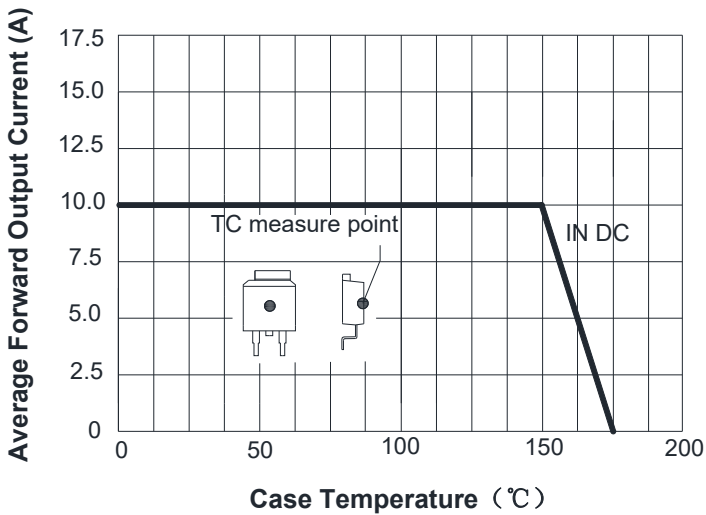


FIG2: Surge Forward Current Capability

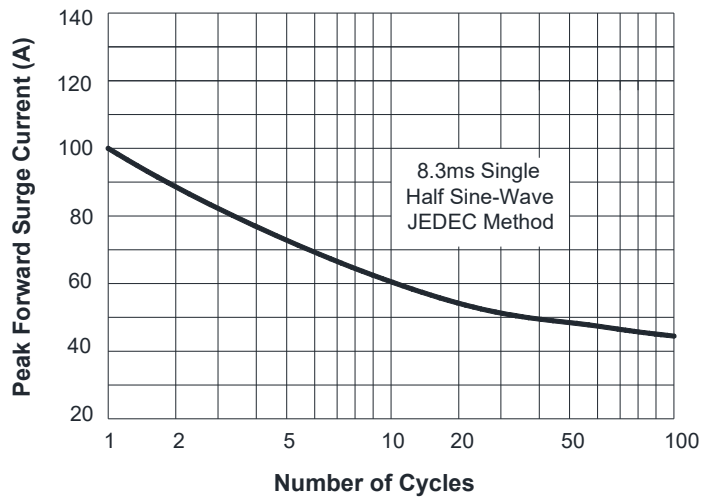


FIG3: Forward Voltage

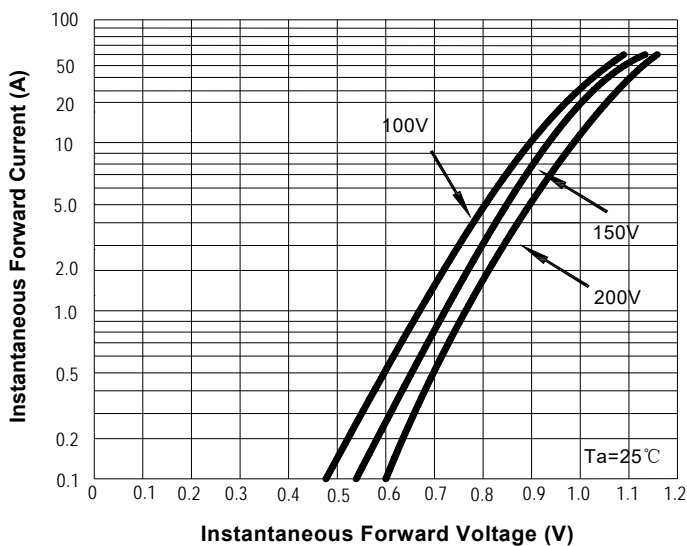
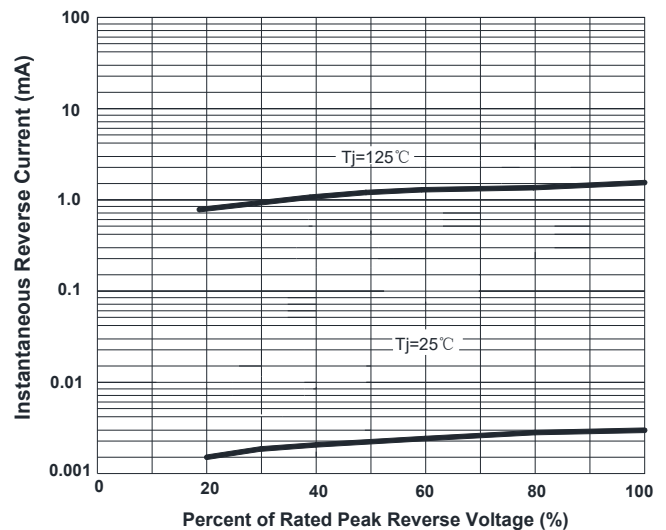


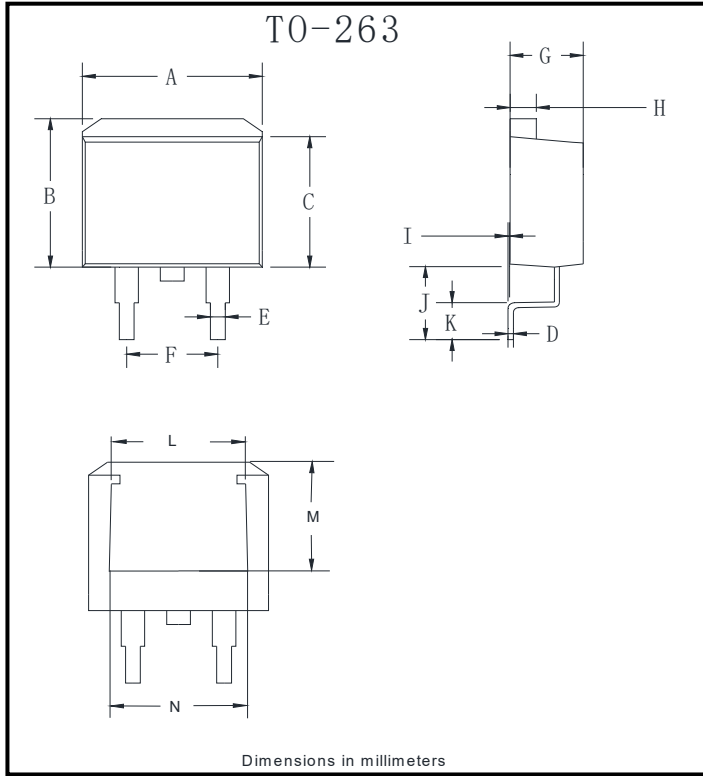
FIG.4: Instantaneous Reverse Characteristics





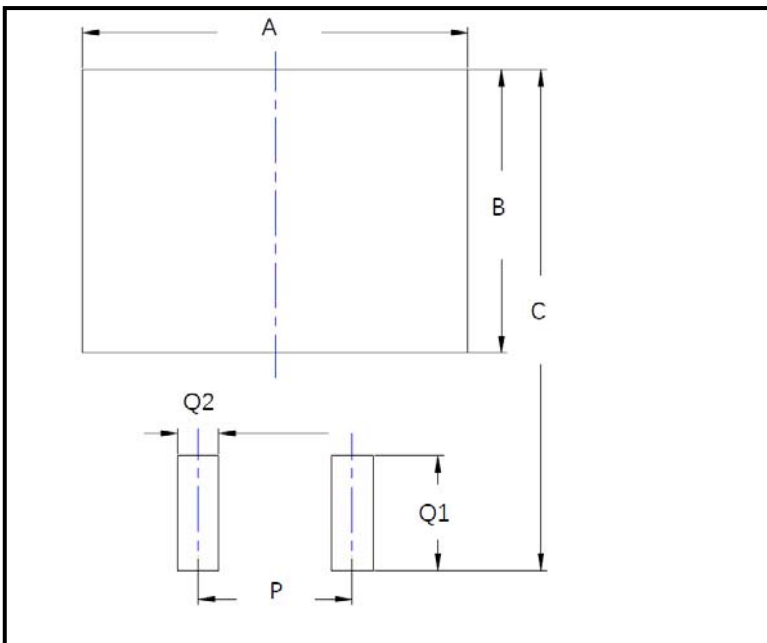
MBRB10100CTS THRU MBRB10200CTS

■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ Suggested Pad Layout



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35



MBRB10100CTS THRU MBRB10200CTS

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The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

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